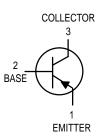
Amplifier Transistors

PNP Silicon





MPS4125

MPS4126

MAXIMUM RATINGS

Rating	Symbol	MPS4125	MPS4126	Unit
Collector-Emitter Voltage	VCE	-30	-25	Vdc
Collector-Base Voltage	VCB	-10	-25	Vdc
Emitter-Base Voltage	VEB	-4.0		Vdc
Collector Current — Continuous	IC	-200		mAdc
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12		W mW/°C
Operating and Storage Junction Temperature Range	TJ, Tstg	-55 to +150		°C



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta}JA$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta}JC$	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic Symbol Min Max Unit **OFF CHARACTERISTICS** Collector-Emitter Breakdown Voltage MPS4125 -30 Vdc V(BR)CEO ____ $(I_{C} = -1.0 \text{ mA}, I_{B} = 0)$ MPS4126 -25 _ Collector-Base Breakdown Voltage MPS4125 -30 Vdc V(BR)CBO ____ -25 $(I_{C} = -10 \ \mu A, I_{E} = 0)$ MPS4126 ____ Emitter–Base Breakdown Voltage ($I_C = 0, I_E = -10 \ \mu A$) Vdc V(BR)EBO -4.0 ____ Collector Cutoff Current ($V_{CB} = -20 V$, $I_E = 0$) -50 nAdc ____ **ICBO** Emitter Cutoff Current ($V_{EB} = -3.0 \text{ V}, I_C = 0$) -50 nAdc **I**EBO _

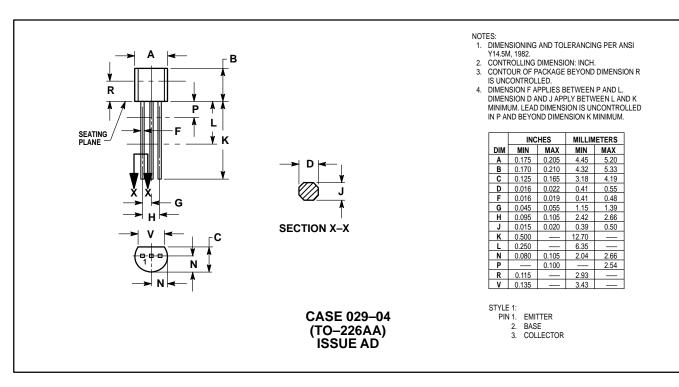


MPS4125 MPS4126

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS					•
DC Current Gain ($I_C = -2.0 \text{ mA}, V_{CE} = -1.0 \text{ V}$) ($I_C = -50 \text{ mA}, V_{CE} = -1.0 \text{ V}$)	MPS4125 MPS4126 MPS4125 MPS4126	hFE	50 120 25 60	150 360 —	_
Collector – Emitter Saturation Voltage $(I_C = -50 \text{ mA}, I_B = -5.0 \text{ mA})$		VCE(sat)	_	-0.4	Vdc
Base-Emitter Saturation Voltage $(I_C = -50 \text{ mA}, I_B = -5.0 \text{ mA})$		V _{BE(sat)}	—	-0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -20$ V, f = 100 MHz)	MPS4125 MPS4126	fT	150 170	_	MHz
Output Capacitance $(V_{CB} = -5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$		C _{ob}	—	4.5	pF
Input Capacitance ($V_{EB} = -0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)	MPS4125 MPS4126	C _{ib}		12 11.5	pF
Small–Signal Current Gain ($I_C = -2.0 \text{ mA}, V_{CE} = 1.0 \text{ V}, f = 1.0 \text{ kHz}$)	MPS4125 MPS4126	h _{fe}	50 120	200 480	—
Noise Figure (I_C = -100 $\mu A, V_{CE}$ = -5.0 V, R_S = 1.0 kΩ, f = 1.0 kHz)	MPS4125 MPS4126	NF		5.0 4.0	dB

PACKAGE DIMENSIONS



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